

THOMSON-CSF COMPONENTS CORPORATION

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VHF COMMUNICATIONS TRANSISTOR

DESCRIPTION

SSM device type SD1416 is a 12.5 volt epitaxial silicon NPN planar transistor designed primarily for VHF communications. This device utilizes "Tuned Q" technology which incorporates a matching network on the input to provide both high gain and broadband operation.

FEATURES

- Designed for VHF military and commercial equipment
- 70.0 watts (min.) with greater than 6.7 dB gain
- Withstands infinite VSWR under operating conditions
- Input matched for wide bandwidth
- High gain

ABSOLUTE MAX. RATING

V_{CBO}	: Collector-Base Voltage	36.0 V
V_{CEO}	: Collector-Emitter Voltage	18.0 V
V_{EBO}	: Emitter-Base Voltage	4.0 V
I_C	: Collector Current (max.)	20.0 A
PT	: Total Device Dissipation @25° Case	220 W
ϕ_{jc}	: Thermal Resistance	.795°C/W
T_j	: Junction Temperature	+200°C
T_s	: Storage Temperature	-65°C to +200°C

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Emitter Breakdown Voltage*	BV_{CEO}	$I_C = 50 \text{ mA}, I_b = 0$	18.0	—	—	V_{dc}
Collector-Emitter Breakdown Voltage*	BV_{CES}	$I_C = 100 \text{ mA}, V_{be} = 0$	36.0	—	—	V_{dc}
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_e = 10 \text{ mA}, I_C = 0$	4.0	—	—	V_{dc}
Collector Cut Off Current	I_{CBO}	$V_{cb} = 15 \text{ V}, I_e = 0$	—	—	5.0	mA
DC Current Gain	h_{FE}	$V_{ce} = 5 \text{ V}, I_C = 10 \text{ A}$	20.0	—	—	—

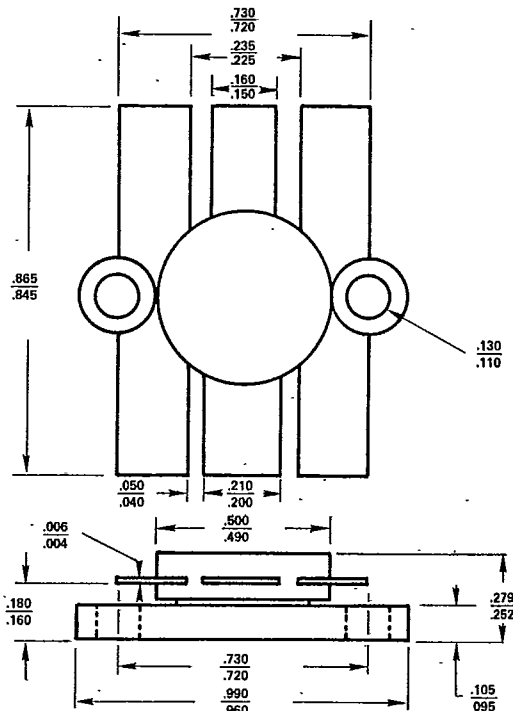
*Pulsed through 25 MH Inductor

RF CHARACTERISTICS: SMALL SIGNAL

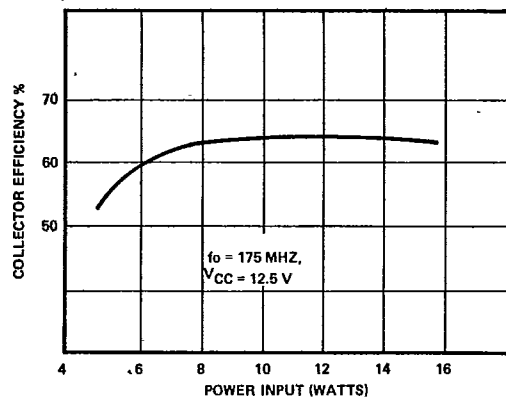
Output Capacitance — $F_o = 1.0 \text{ MHz}$	C_{ob}	$V_{cb} = 12.5 \text{ V}, I_C = 0$	—	—	300.0	pF
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RF CHARACTERISTICS: LARGE SIGNAL

Amplifier power out	P_o	175 MHz/12.5 V	70.0	—	—	watts
Amplifier power gain	P_g		6.7	—	—	dB
Impedance — Input	Z_s	175 MHz/12.5 V	.58 + J .44			ohms
Impedance — Output	Z_{cl}		.72 + J .44			ohms



.500 6LFL

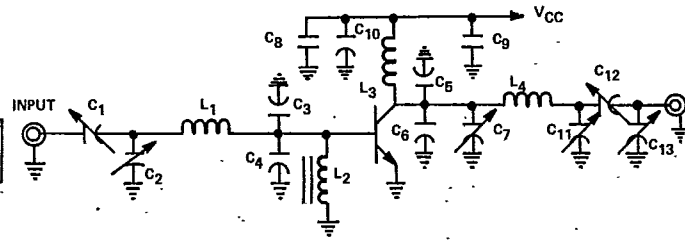
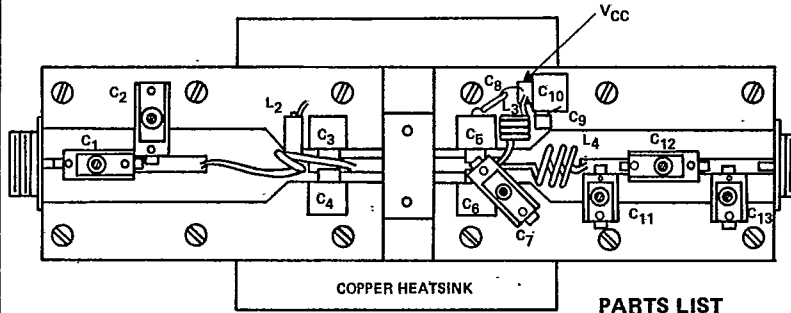


COLLECTOR EFFICIENCY VS. POWER INPUT

SD1416

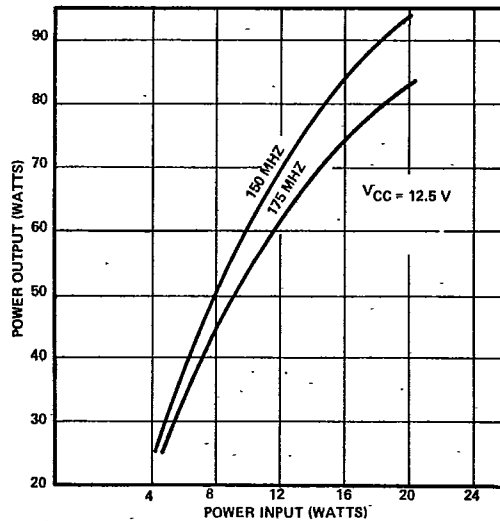
IMPEDANCE VS. FREQUENCY

V _{CC}	P _{IN} (W)	f _o (MHz)	Z _{SOURCE}	Z _{LOAD}
12.5 V	15.0	175.	.58 + J.44 Ω	.72 + J.44 Ω
12.5 V	15.0	150.	.58 + J.44 Ω	.72 + J.87 Ω



PARTS LIST

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|---|--|-----------------|-----------------------------------|
| C ₁ , C ₇ | ARCO 423 MICA CAP. - 7 pf → 100 pf | C ₁₁ | ARCO 400 MICA CAP. - .1 pf → 7 pf |
| C ₂ , C ₁₂ | ARCO 422 MICA CAP. - 4 pf → 40 pf | C ₁₃ | ARCO 404 MICA CAP. - 8 pf → 60 pf |
| C ₃ , C ₄ , C ₅ , C ₆ | UNELCO BOOK MICA CAP. - 100 pf @ 350 VDC | L ₁ | IT #12 TCB .25" I.D. |
| C ₈ | ERIE DISC. CAP. - .01 μf @ 200 VDC | L ₂ | FERROXCUBE VK200 |
| C ₉ | ERIE MONOLITHIC CAP. - .22 μf @ 50 VDC | L ₃ | 4T #12 TCB CLOSE SPACED .25" ID. |
| C ₁₀ | UNELCO BOOK MICA. - 1000 pf @ 350 VDC | L ₄ | 3T #12 TCB SPACED #10 .5" ID |



POWER OUTPUT VS. POWER INPUT